

# DC COMPONENTS CO., LTD.

## RECTIFIER SPECIALISTS

KBPC / MB 15005 / 1505 THRU KBPC / MB 1510 / 1510

# TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER VOLTAGE RANGE - 50 to 1000 Volts CURRENT - 15 Amperes

## **FEATURES**

- \* Metal case for Maximum Heat Dissipation
- \* Surge overload ratings-300 Amperes
- \* Low forward voltage drop

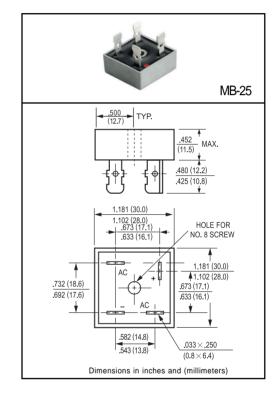
## MECHANICAL DATA

- \* Case: Metal case, electrically isolated \* Epoxy: UL 94V-0 rate flame retardant
- \* Terminals: Plated .25"(6.35mm) Faston lugs, Solderable per MIL-STD-202E. Method 208 guaranteed

\* Polarity: As marked \* Mounting position: Any \* Weight: 30 grams

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



			KBPC 15005	KBPC 1501	KBPC 1502	KBPC 1504	KBPC 1506	KBPC 1508	KBPC 1510	
		SYMBOL	MB1505	MB151	MB152	MB154	MB156	MB158	MB1510	UNITS
Maximum Recurrent Peak Reverse Voltage		VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current at Tc = 55°C		lo	15.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)		IFSM	300							Amps
Maximum Forward Voltage Drop per element at 7.5A DC		VF	1.1						Volts	
Maximum DC Reverse Current at Rated	@TA = 25°C	- IR	10							
DC Blocking Voltage per element	@Tc = 100°C	- IK	500							
I <sup>2</sup> t Rating for Fusing (t<8.3ms)		l <sup>2</sup> t	374							A <sup>2</sup> Sec
Typical Junction Capacitance ( Note1)		Cı	40							pF
Typical Thermal Resistance (Note 2)		RθJA	19						°C/W	
Operating and Storage Temperature Range		TJ,TSTG	-55 to + 175							°C

NOTES: 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts

2. Thermal Resistance from Junction to Ambient and from junction to lead mounted on P.C.B. with 0.47 x 0.47" (12x12mm) copper pads.

SURGE CURRENT 500 8.3ms Single Half Sine-Wave (JEDEC Method) 400 300

PEAK FORWARD SURGE CURRENT, (A)

200

100

0

1 2 4

6 8 10

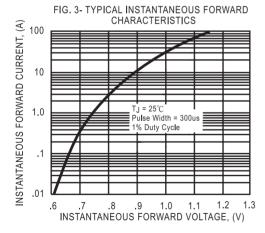
NUMBER OF CYCLES AT 60Hz

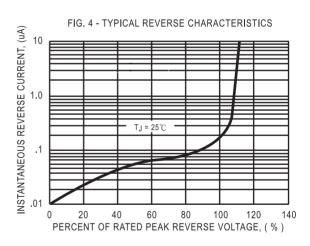
20

40

FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD 60 80 100

FIG. 2 - TYPICAL FORWARD CURRENT **DERATING CURVE** 25 AVERAGE FORWARD CURRENT, (A) 20 15 10 Single Phase Half Wave 60Hz Indutive or 5 Resistive Load 0 0 50 100 150 175 CASE TEMPERATURE, (°C )









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TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts

CURRENT - 15 Amperes

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## MECHANICAL DATA

\* Case: Metal, electrically isolated

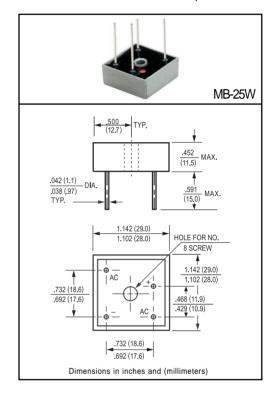
\* Epoxy: UL 94V-0 rate flame retardant

\* Lead: MIL-STD-202E, Method 208 guaranteed

\* Polarity: As marked \* Mounting position: Any \* Weight: 30 grams

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



		KBPC 15005W	KBPC 1501W	KBPC 1502W	KBPC 1504W	KBPC 1506W	KBPC 1508W	KBPC 1510W	ĺ	
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I <sup>2</sup> t Rating for Fusing (t<8.3ms)		I <sup>2</sup> t	374							A <sup>2</sup> Sec
Typical Junction Capacitance ( Note1)		Cı	300							pF
Typical Thermal Resistance (Note 2)		RθJC	2.5							°C/W
Operating and Storage Temperature Range		TJ,TSTG	-55 to + 150							۰c

NOTES : 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts

<sup>2.</sup> Thermal Resistance from Junction to Case per leg.

HRU KBPC1510W MB1510W

SURGE CURRENT

500

8.3ms Single Half Sine-Wave (JEDEC Method)

100

100

6 8 10

NUMBER OF CYCLES AT 60Hz

20

40

60 80 100

4

1 2

FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD

FIG. 2 - TYPICAL FORWARD CURRENT **DERATING CURVE** 25 AVERAGE FORWARD CURRENT, (A) 20 15 10 Single Phase Half Wave 60Hz Indutive or 5 Resistive Load 0 0 50 100 150 175 CASE TEMPERATURE, (°C )

